

## KSD1021

## **Audio Frequency Power Amplifier**

Complement to KSB811
Collector Current : I<sub>C</sub>=1A

• Collector Dissipation : P<sub>C</sub>=350mW



1.Emitter 2. Collector 3. Base

# **NPN Epitaxial Silicon Transistor**

## **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V <sub>CBO</sub>	Collector-Base Voltage	40	V
V <sub>CEO</sub>	Collector-Emitter Voltage	30	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current	1	A
P <sub>C</sub>	Collector Power Dissipation	350	mW
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

## **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C=100\mu A, I_E=0$	40			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =10mA, I <sub>B</sub> =0	30			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =100μA, I <sub>C</sub> =0	5			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB}$ =30V, $I_{E}$ =0			0.1	μΑ
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> =1V, I <sub>C</sub> =100mA	120		400	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =1A, I <sub>B</sub> =0.1A			0.5	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> =1A, I <sub>B</sub> =0.1A			1.2	V
f <sub>T</sub>	Current Gain Band Width Product	V <sub>CE</sub> =6V, I <sub>C</sub> =10mA		130		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =6V, I <sub>E</sub> =0, f=1MHz		16		pF

## **h**<sub>FE</sub> Classification

Classification	Y	G	
h <sub>FE</sub>	120 ~ 240	200 ~ 400	

# **Typical Characteristics**

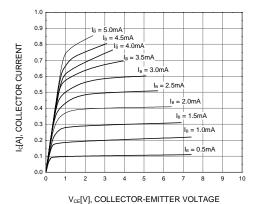


Figure 1. Static Characteristic

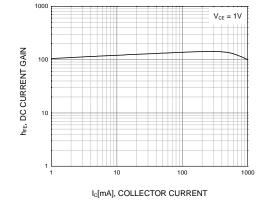


Figure 2. DC current Gain

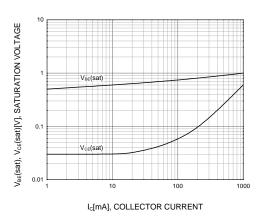


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

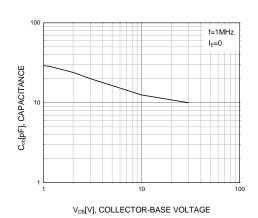


Figure 4. Collector Output Capacitance

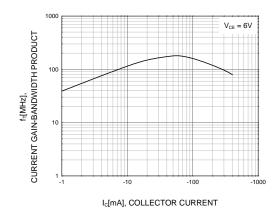


Figure 5. Current Gain Bandwidth Product

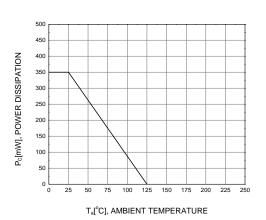
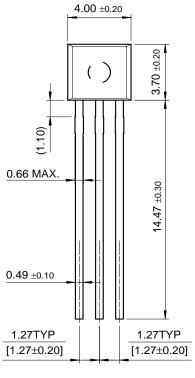


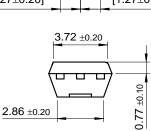
Figure 6. Power Derating

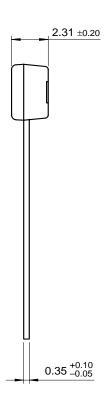
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# **Package Dimensions**

# **TO-92S**







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Bott	omless™	FASTr™	LittleFET™	Power247™	SuperFET™
Coo	IFET™	FPS™	MICROCOUPLER™	PowerSaver™	SuperSOT™-3
CR	OSSVOLT™	FRFET™	MicroFET™	PowerTrench <sup>®</sup>	SuperSOT™-6
DO	ЛЕ™	GlobalOptoisolator™	MicroPak™	QFET <sup>®</sup>	SuperSOT™-8
Eco	SPARK™	GTO™	MICROWIRE™	QS <sup>TM</sup>	SyncFET™
$E^2C$	MOS™	HiSeC™	MSX <sup>TM</sup>	QT Optoelectronics™	TinyLogic <sup>®</sup>
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Programmable Active Droop™		OPTOPLANAR™	SMART START™	VCX <sup>TM</sup>	
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